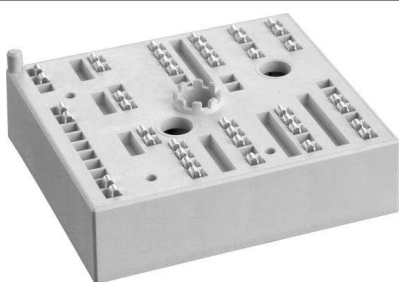


SKiiP 28AHB16V1



MiniSKiiP® 2

3-phase bridge rectifier +
brake chopper

SKiiP 28AHB16V1

Features

- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

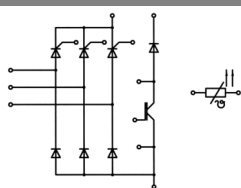
- Input bridge for inverter up to 39 kVA

Remarks

- V_{CEsat} , V_F = chip level value

Absolute Maximum Ratings		$T_s = 25\text{ °C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT - Chopper			
V_{CES}	$T_s = 25\text{ (70) °C}$	1200	V
I_C	$t_p \leq 1\text{ ms}$	118 (88)	A
I_{CRM}		210	A
V_{GES}		± 20	V
T_j		- 40 ... + 150	°C
Diode - Chopper			
I_F	$T_s = 25\text{ (70) °C}$	118 (88)	A
I_{FRM}	$t_p \leq 1\text{ ms}$	210	A
T_j		- 40 ... + 150	°C
Diode / Thyristor - Rectifier			
V_{RRM}	$T_s = 70$	1600	V
I_F / I_T	$t_p = 10\text{ ms}$, $\sin 180^\circ$, $T_j = 25\text{ °C}$	82	A
I_{FSM} / I_{TSM}	$t_p = 10\text{ ms}$, $\sin 180^\circ$, $T_j = 25\text{ °C}$	1000	A
i^2t	Diode	5500	A ² s
T_j	Thyristor	- 40 ... + 150	°C
T_j		- 40 ... + 125	°C
I_{RMS}	per power terminal (20 A / spring)	120	A
T_{stg}	$T_{op} \leq T_{stg}$	- 40 ... + 125	°C
V_{isol}	AC, 1 min.	2500	V

Characteristics		$T_s = 25\text{ °C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT - Chopper					
V_{CEsat}	$I_{Cnom} = 105\text{ A}$, $T_j = 25\text{ (125) °C}$		1,7 (2)	2,1 (2,4)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 3\text{ mA}$	5	5,8	6,5	V
$V_{CE(TO)}$	$T_j = 25\text{ (125) °C}$		1 (0,9)	1,2 (1,1)	V
r_T	$T_j = 25\text{ (125) °C}$		6,7 (10)	8,6 (12)	mΩ
C_{ies}	$V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$		8,4		nF
C_{oes}	$V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$		1,5		nF
C_{res}	$V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$		1,1		nF
$R_{th(j-s)}$	per IGBT		0,4		K/W
$t_{d(on)}$	under following conditions		65		ns
t_r	$V_{CC} = 600\text{ V}$, $V_{GE} = \pm 15\text{ V}$		30		ns
$t_{d(off)}$	$I_{Cnom} = 105\text{ A}$, $T_j = 125\text{ °C}$		410		ns
t_f	$R_{Gon} = R_{Goff} = 5,5\text{ Ω}$		100		ns
E_{on}	inductive load		14,4		mJ
E_{off}			13,3		mJ
Diode - Chopper					
$V_F = V_{EC}$	$I_{Fnom} = 105\text{ A}$, $T_j = 25\text{ (125) °C}$		1,6 (1,6)	1,8 (1,8)	V
$V_{(TO)}$	$T_j = 25\text{ (125) °C}$		1 (0,8)	1,1 (0,9)	V
r_T	$T_j = 25\text{ (125) °C}$		5,7 (7,6)	6,7 (8,6)	mΩ
$R_{th(j-s)}$	per diode		0,55		K/W
I_{RRM}	under following conditions		160		A
Q_{rr}	$I_{Fnom} = 105\text{ A}$, $V_R = 600\text{ V}$		26		μC
E_{rr}	$V_{GE} = 0\text{ V}$, $T_j = 125\text{ °C}$		10,8		mJ
	$di_F/dt = 5400\text{ A/μs}$				



AHB

Characteristics		$T_s = 25\text{ °C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
Diode - Rectifier					
V_F	$I_{Fnom} = 75\text{ A}$, $T_j = 25\text{ °C}$		1,2		V
$V_{(TO)}$	$T_j = 150\text{ °C}$		0,8		V
r_T	$T_j = 150\text{ °C}$		7		mΩ
$R_{th(j-s)}$	per diode		0,7		K/W
Thyristor - Rectifier					
V_T	$I_{Fnom} = 120\text{ A}$, $T_j = 25\text{ (125) °C}$			1,8 (1,7)	V
$V_{T(TO)}$	$T_j = 125\text{ °C}$			1,1	V
r_T	$T_j = 125\text{ °C}$			5	mΩ
V_{GT}	$T_j = 25\text{ °C}$			3	V
I_{GT}	$T_j = 25\text{ °C}$	150			mA
I_H	$T_j = 25\text{ °C}$		200		mA
I_L	$T_j = 25\text{ °C}$		400		mA
$dv/dt_{(cr)}$	$T_j = 125\text{ °C}$			1000	V/μs
$di/dt_{(cr)}$	$T_j = 125\text{ °C}$			50	A/μs
$R_{th(j-s)}$	per thyristor		0,65		K/W
Temperature Sensor					
R_{ts}	3 %, $T_r = 25\text{ (100) °C}$		1000(1670)		Ω
Mechanical Data					
w			65		g
M_s	Mounting torque	2		2,5	Nm

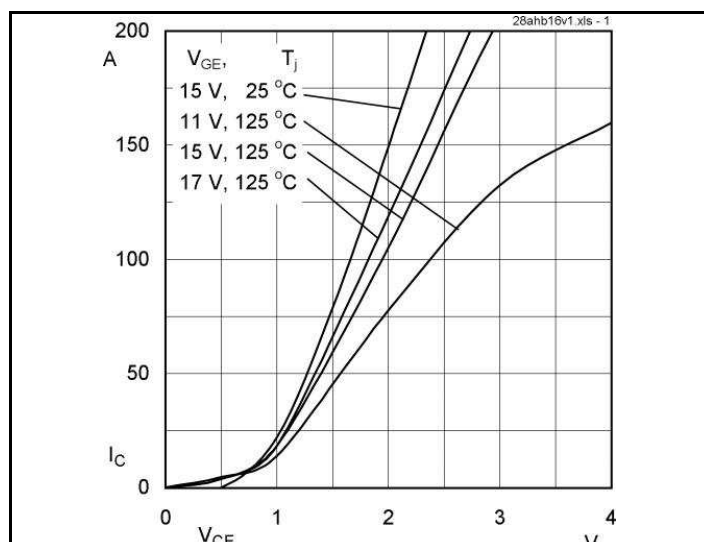


Fig. 1 Typ. output characteristic

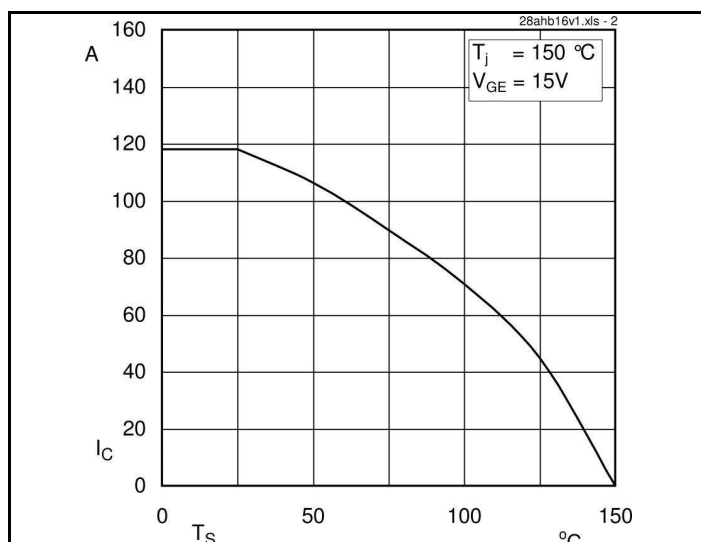


Fig. 2 Typ. rated current vs. temperature

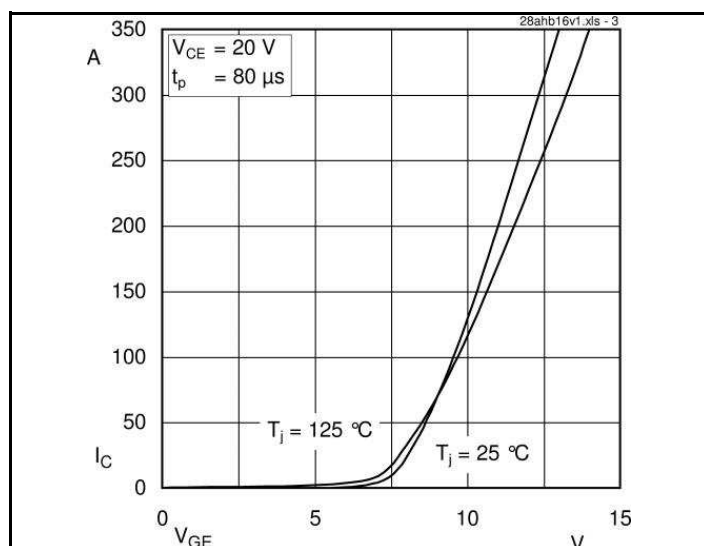


Fig. 3 Typ. transfer characteristic

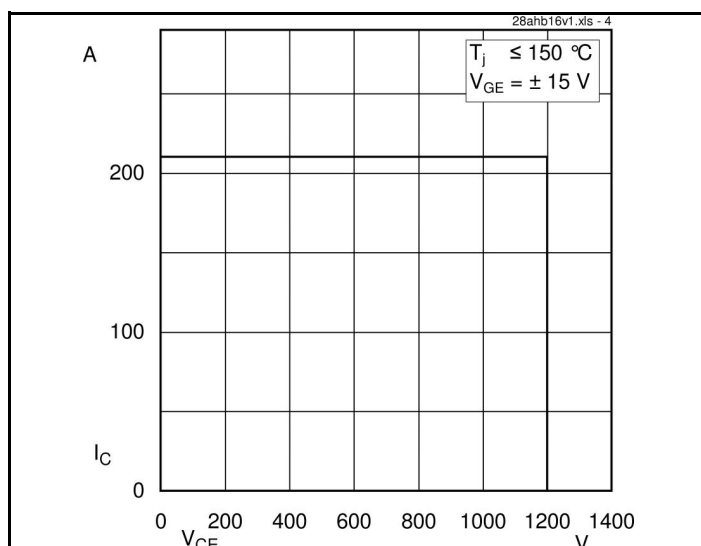


Fig. 4 Reverse bias safe operating area

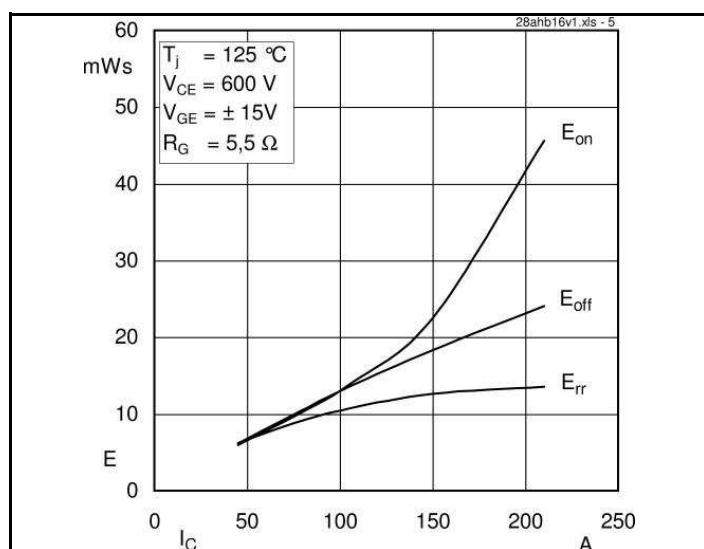


Fig. 5 Typ. Turn-on /-off energy = $f(I_C)$

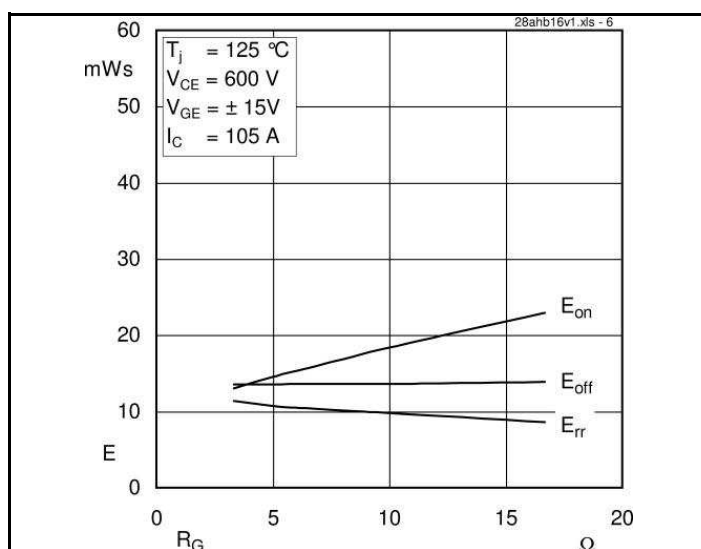
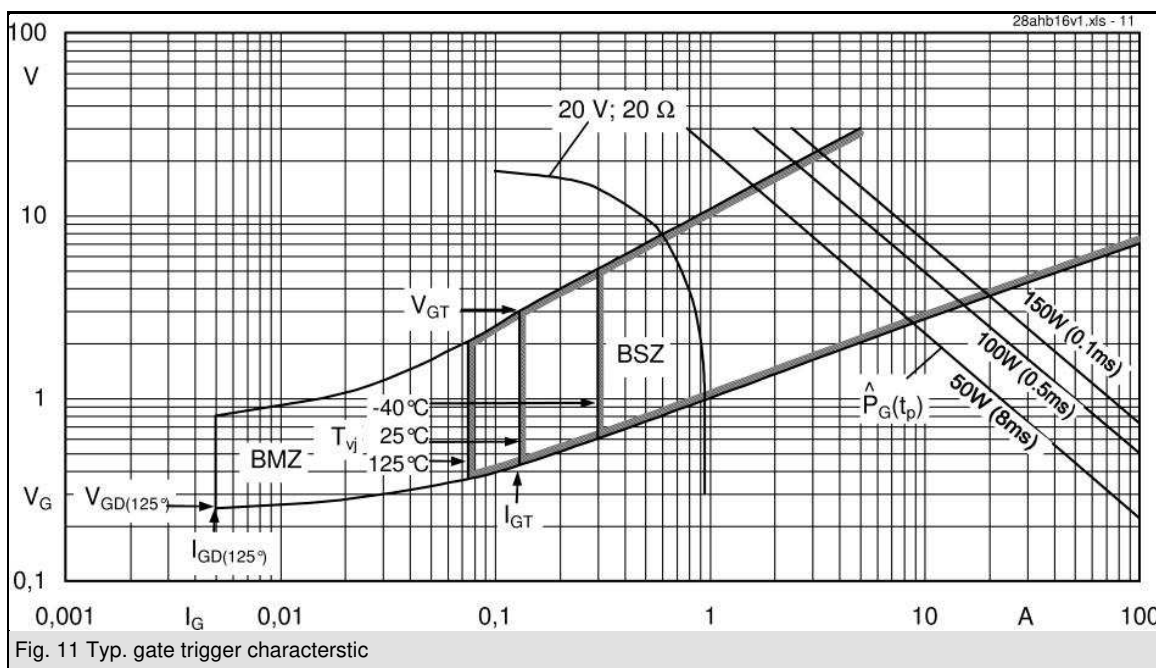
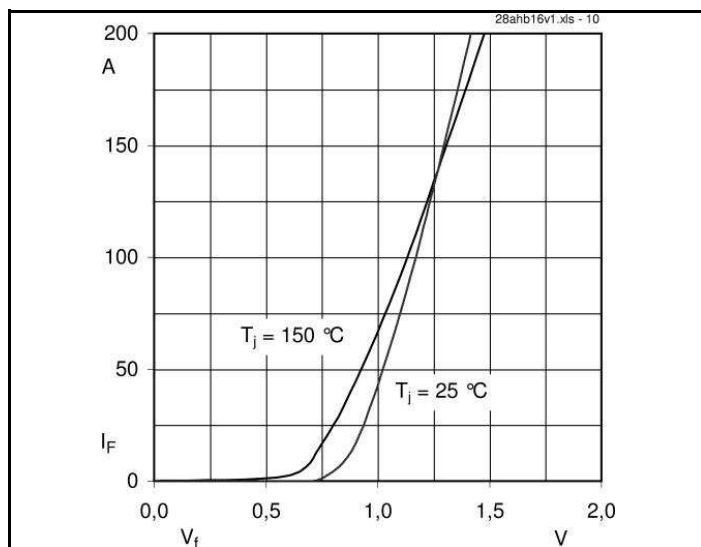
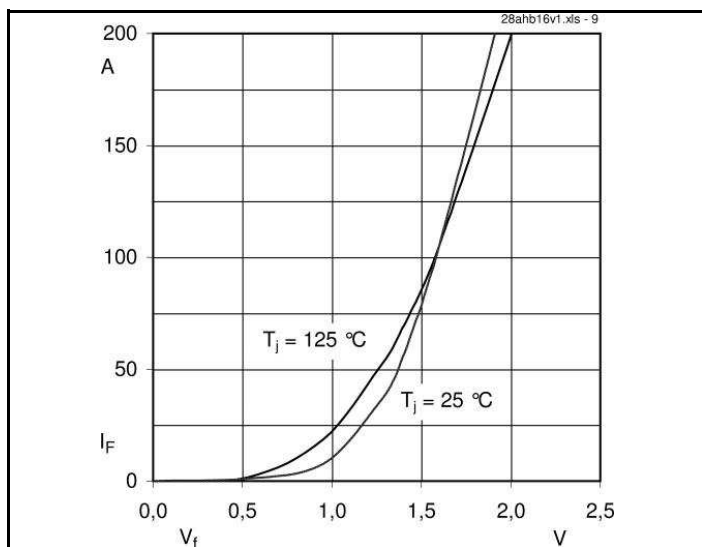
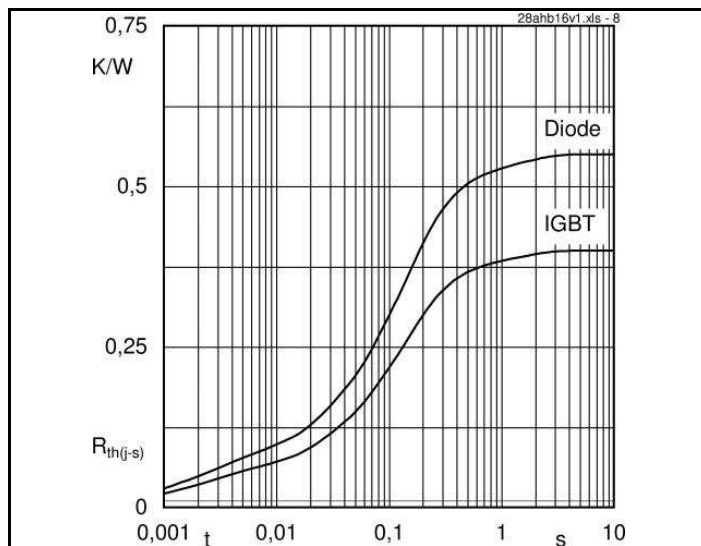
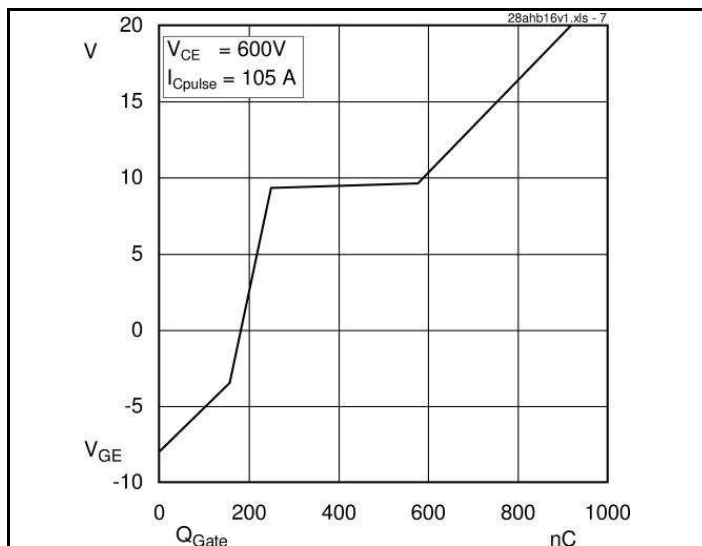
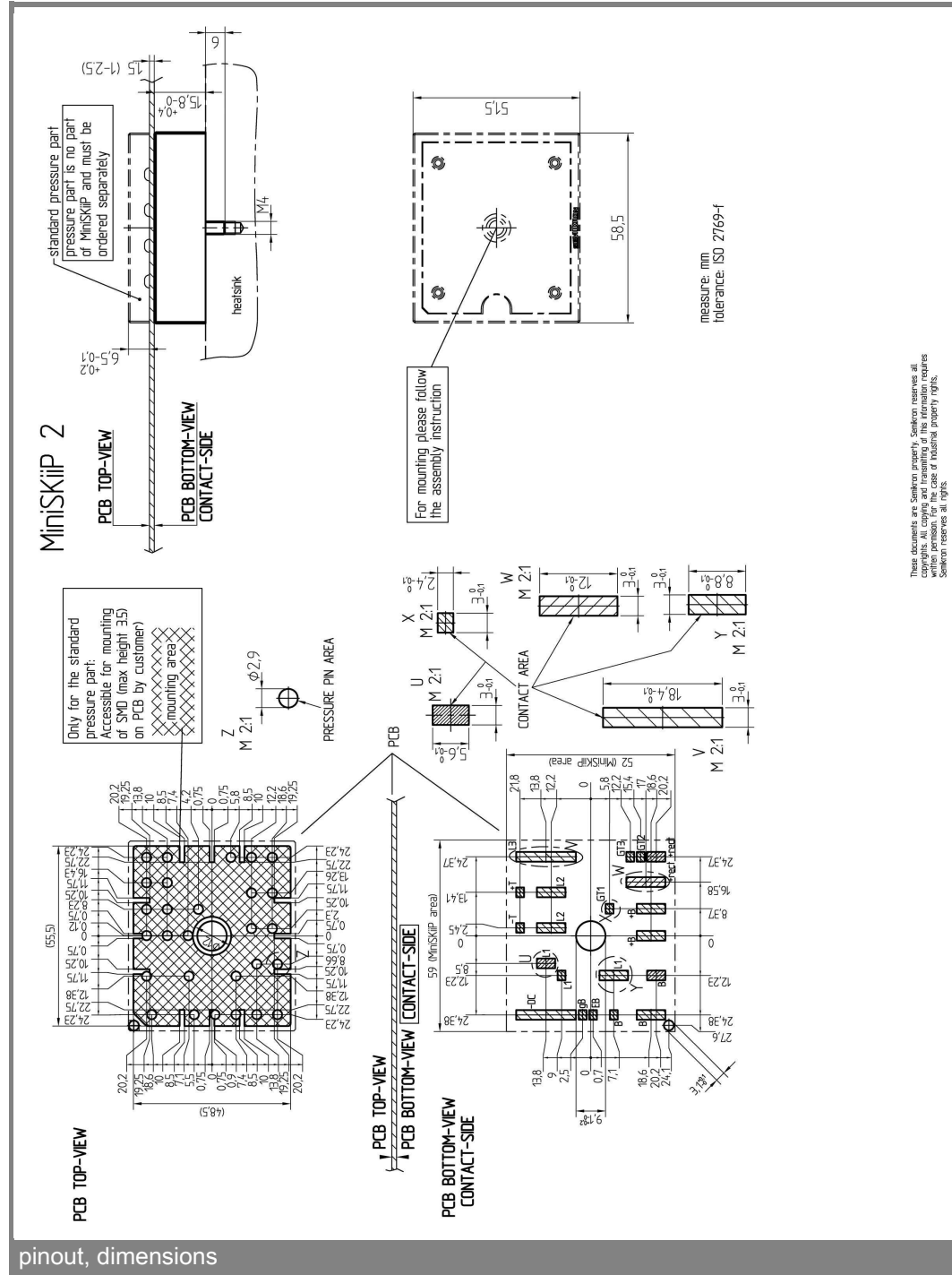
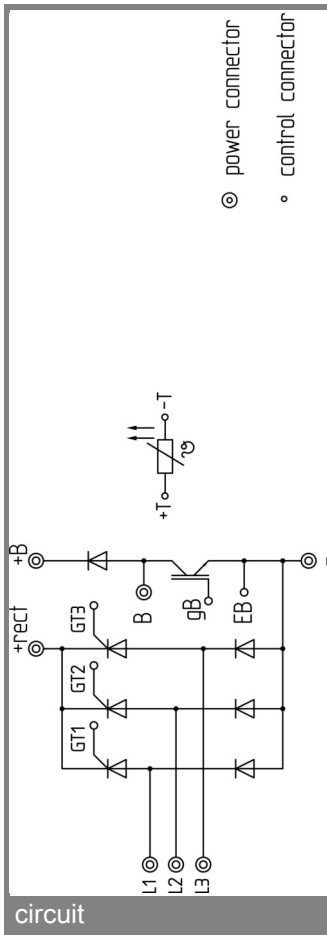


Fig. 6 Typ. Turn-on /-off energy = $f(R_G)$





This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.